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Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	30	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current Continuous (V_{GS} = 10V, T_C < 163°C)	80	А
I _D	Continuous ($V_{GS} = 5V$, $T_C < 162^{\circ}C$)	80	A
	Continuous (V _{GS} = 10V, T _C = 25°C, with $R_{\theta JA}$ = 43°C/W)	31	Α
	Pulsed	Figure 4	A
E _{AS}	SinglePulseAvalancheEnergy (Note1)	947	mJ
D	Power Dissipation	254	W
P _D	Derate above 25°C	1.7	W/ºC
T _J , T _{STG}	Operating and Storage Temperature	-55 to +175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case	0.59	°C/W
$R_{\theta J A}$	Thermal Resistance Junction to Ambient (Note 2)	62	°C/W
$R_{ hetaJA}$	Thermal Resistance Junction to Ambient TO-263,1in ² copper pad area	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8860	FDB8860	TO-263AB	330mm	24mm	800units

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Co	nditions	Min	Тур	Max	Units
Off Chara	acteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 1mA, V_{GS}$	= 0V	30	-	-	V
 	Zero Gate Voltage Drain Current	$V_{DS} = 24V$		-	-	1	μA
DSS	Zero date voltage Brain ourient	$V_{GS} = 0V$	T _J = 150°C	-	-	250	μΛ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1	1.7	3	V
		I _D = 80A, V _{GS} = 10V	-	1.6	2.3	
		I _D = 80A, V _{GS} = 5V	-	1.9	2.6	
R _{DS(ON)}	Drain to Source On Resistance	I _D = 80A, V _{GS} = 4.5V	-	2.1	2.7	mΩ
		I _D = 80A, V _{GS} = 10V, T _J = 175°C	-	2.5	3.6	

Dynamic Characteristics

CISS	Input Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		-	9460	12585	pF
C _{OSS}	Output Capacitance			-	1710	2275	pF
C _{RSS}	Reverse Transfer Capacitance			-	1050	1575	pF
R _G	Gate Resistance	f = 1MHz		-	1.8	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0V$ to 10V		-	165	214	nC
Q _{g(5)}	Total Gate Charge at 5V	$V_{GS} = 0V$ to 5V]., . <u>.</u> ,,	-	89	115	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{GS} = 0V$ to 1V	V _{DD} = 15V I _D = 80A	-	9.1	12	nC
Q _{gs}	Gate to Source Gate Charge		$I_{\rm D} = 0.0$ A	-	26	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		Ig= 1.011A	-	18	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	33	-	nC

Characteristics					
Characteristics					
Turn-On Time		-	-	340	ns
Turn-On Delay Time	V _{DD} = 15V, I _D = 80A	-	14	-	ns
Turn-On Rise Time		-	213	-	ns
Turn-Off Delay Time	$V_{GS} = 5V, R_{GS} = 1\Omega$	-	79	-	ns
Turn-Off Fall Time		-	49	-	ns
Turn-Off Time		-	-	192	ns
	Turn-On Time Turn-On Delay Time Turn-On Rise Time Turn-Off Delay Time Turn-Off Fall Time	Turn-On TimeTurn-On Delay TimeTurn-On Rise TimeVDD = 15V, ID = 80ATurn-Off Delay TimeTurn-Off Fall Time	$\begin{tabular}{ c c c c c } \hline Turn-On Time & & & & & & & \\ \hline Turn-On Delay Time & & & & & \\ \hline Turn-On Rise Time & & & & & \\ \hline Turn-Off Delay Time & & & & & \\ \hline Turn-Off Fall Time & & & & & \\ \hline \hline \\ \hline \end{tabular}$	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$

I _{SD} = 80A	-	-
I _{SD} = 40A	-	-
$I_{SD} = 80A$, $dI_{SD}/dt = 100A/\mu s$	-	-
$I_{SD} = 80A$, $dI_{SD}/dt = 100A/\mu s$	-	-

t_{rr} Q_{rr}

Notes: 1: Starting T_J = 25°C, L =0.47mH, I_{AS} = 64A , V_{DD} = 30V, V_{GS} = 10V. 2: Pulse width = 100s

Reverse Recovery Time

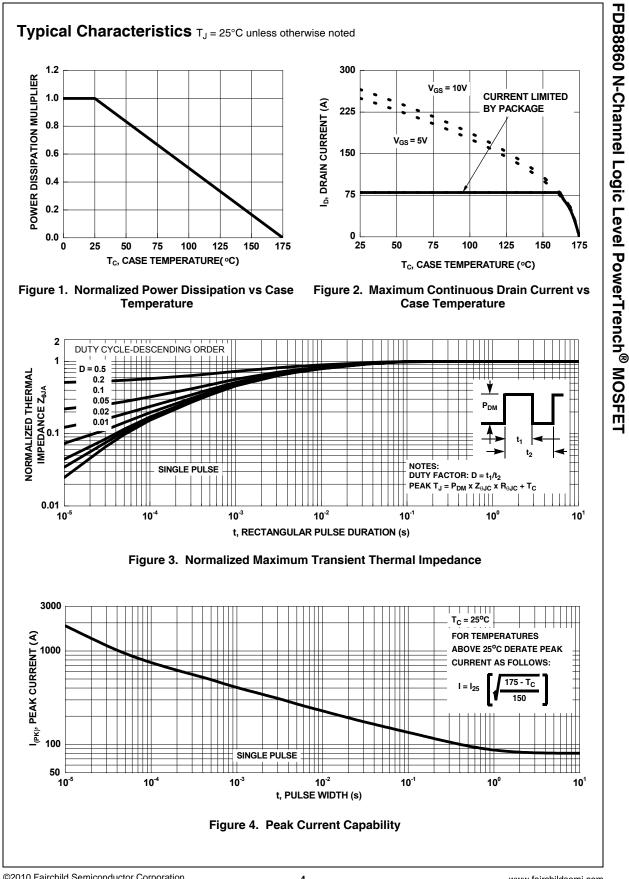
Reverse Recovery Charge

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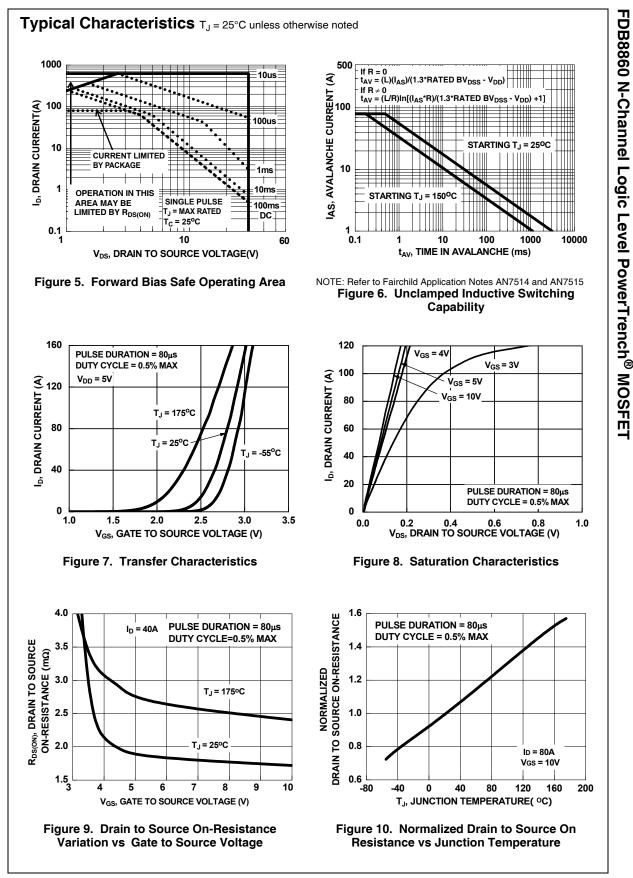
29

ns

nC

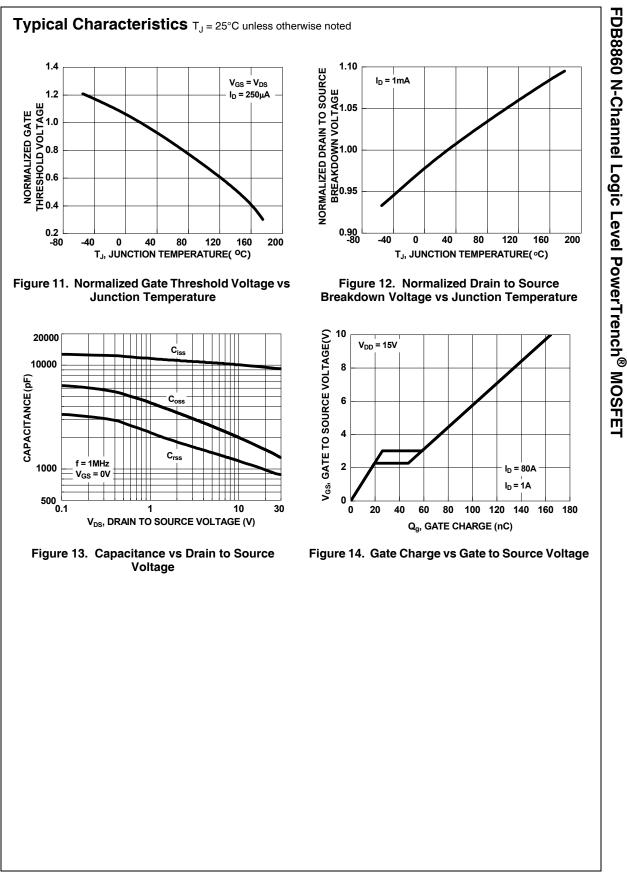


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